MMVL3700T1

High Voltage Silicon Pin Diode

These devices are designed primarily for VHF band switching applications but are also suitable for use in general-purpose switching circuits. They are supplied in a cost-effective plastic surface mount package for economical, high-volume consumer and industrial requirements.

Features

- Long Reverse Recovery Time: $t_{rr} = 300 \text{ ns} (Typ)$
- Rugged PIN Structure Coupled with Wirebond Construction for Optimum Reliability
- Low Series Resistance @ 100 MHz:
 - $R_S = 0.7 \ \Omega$ (Typ) @ $I_F = 10 \ mAdc$
- Reverse Breakdown Voltage = 200 V (Min)
- Pb–Free Package is Available

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Continuous Reverse Voltage	V _R	200	Vdc
Peak Forward Current	١ _F	20	mAdc

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation FR-5 Board, $T_A = 25^{\circ}C$ (Note 1) Derate above 25°C	P _D	200 1.57	mW mW/°C
Thermal Resistance, Junction-to-Ambient	R_{\thetaJA}	635	°C/W
Junction and Storage Temperature	T _J , T _{stg}	150	°C

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

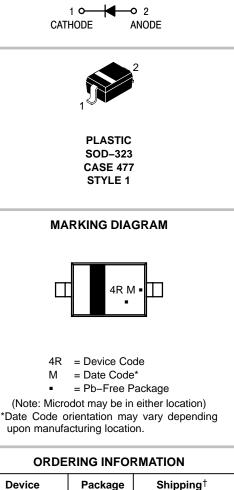
1. FR-4 Minimum Pad



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SILICON PIN SWITCHING DIODE



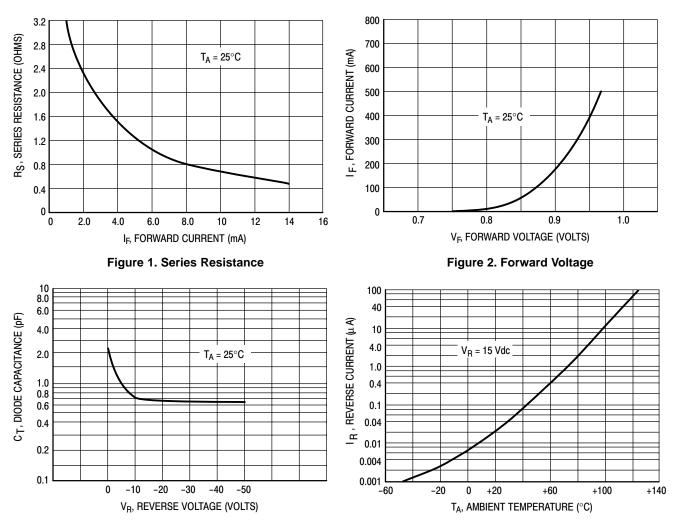
Device	Package	Shipping [†]
MMVL3700T1	SOD-323	3000/Tape & Reel
MMVL3700T1G	SOD-323 (Pb-Free)	3000/Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

MMVL3700T1

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

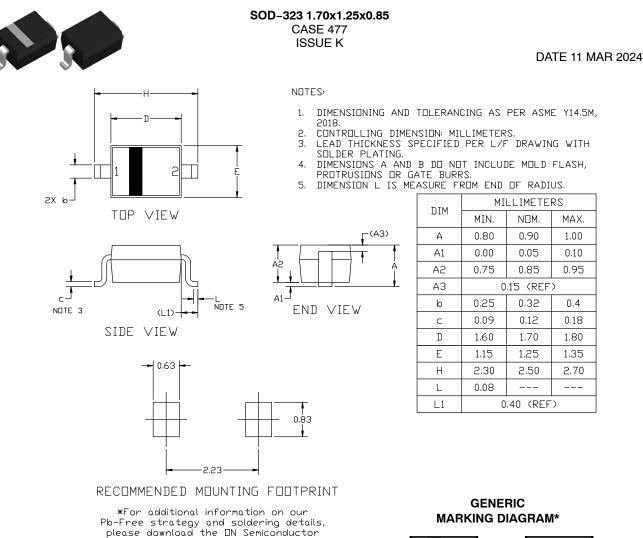
Characteristic	Symbol	Min	Тур	Max	Unit
Reverse Breakdown Voltage ($I_R = 10 \ \mu Adc$)	V _{(BR)R}	200	-	-	Vdc
Diode Capacitance (V _R = 20 Vdc, f = 1.0 MHz)	C _T	-	-	1.0	pF
Series Resistance (I _F = 10 mAdc)	R _S	-	0.7	1.0	Ω
Reverse Leakage Current (V _R = 150 Vdc)	I _R	-	-	0.1	μAdc
Reverse Recovery Time $(I_F = I_R = 10 \text{ mAdc})$	t _{rr}	-	300	-	ns



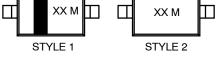
TYPICAL CHARACTERISTICS

Figure 3. Diode Capacitance

Figure 4. Leakage Current



Soldering and Mounting Techniques Reference manual, SOLDERRM/D.



XX = Specific Device Code M = Date Code

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

STYLE 2: NO POLARITY STYLE 1: PIN 1. CATHODE (POLARITY BAND) 2. ANODE

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DESCRIPTION:	SOD-323 1.70x1.25x0.85		PAGE 1 OF 1		
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